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## SDUR60P60W ULTRAFAST PLASTIC RECTIFIER

## Applications:

- Antiparallel diode for high frequency switching devices
- Anti saturation diode
- Snubber diode
- Free wheeling diode in converters and motor control circuits
- Rectifiers in switch mode power supplies (SMPS)
- Inductive heating and melting
- Uninterruptible power supplies (UPS)
- Ultrasonic cleaners and welders


## Features:

- Ultra-Fast Switching
- High Current Capability
- Low Reverse Leakage Current
- High Surge Current Capability
- Plastic Material has UL Flammability Classification 94V-O
- This is a Pb - Free Device
- All SMC parts are traceable to the wafer lot

1. Cathode
2.Anode

- Additional testing can be offered upon request

Mechanical Dimensions: In mm


| SYMBOL | MIN. | TYP. | MAX. |
| :---: | :---: | :---: | :---: |
| A | 4.80 | 5.00 | 5.20 |
| A1 | 2.21 | 2.41 | 2.61 |
| A2 | 1.90 | 2.00 | 2.10 |
| b | 1.10 | 1.20 | 1.35 |
| b1 |  | 2.00 |  |
| b2 |  | 3.00 |  |
| c | 0.55 | 0.60 | 0.75 |
| D | 20.80 | 21.00 | 21.20 |
| D1 |  | 16.55 |  |
| D2 |  | 1.20 |  |
| E | 15.6 | 15.8 | 16.0 |
| E1 |  | 13.30 |  |
| E2 |  | 5.00 |  |
| E3 |  | 2.50 |  |
| e |  | 5.44 |  |
| L | 19.42 | 19.92 | 20.42 |
| L1 |  | 4.13 |  |
| L2 |  | 2.15 |  |
| P | 3.50 | 3.60 | 3.70 |
| P1 | - | - | 7.40 |
| P2 |  | 2.50 |  |
| Q |  | 5.80 |  |
| S | 6.05 | 6.15 | 6.25 |
| T |  | 10.00 |  |
| U |  | 6.20 |  |
|  |  |  |  |

TO-247AC

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## Marking Diagram:



Where $X X X X X$ is $Y Y W W L$

| SDUR | $=$ Device Type |
| :--- | :--- |
| 60 | $=$ Forward Current $(60 \mathrm{~A})$ |
| P | $=\mathrm{T}_{\mathrm{j}}=175^{\circ} \mathrm{C}$ |
| 60 | $=$ Reverse Voltage $(600 \mathrm{~V})$ |
| W | $=$ Configuration |
| SSG | $=$ SSG |
| YY | $=$ Year |
| WW | $=$ Week |
| L | $=$ Lot Number |

Cautions: Molding resin
Epoxy resin UL:94V-0

## Ordering Information:

| Device | Package | Shipping |
| :--- | :---: | :---: |
| SDUR60P60W | TO-247AC <br> (Pb-Free) | $25 \mathrm{pcs} /$ tube |

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.

## Maximum Ratings:

| Characteristics | Symbol | Condition | Max. | Units |
| :---: | :---: | :---: | :---: | :---: |
| Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage | VRRM <br> $V_{\text {RWM }}$ $V_{R}$ | - | 600 | V |
| Average Rectified Forward Current | IF (AV) | $50 \%$ duty cycle $@ T_{c}=70^{\circ} \mathrm{C}$, rectangular wave form | 60 | A |
| Peak One Cycle Non-Repetitive Surge Current | Ifsm | 8.3ms, Half Sine pulse | 400 | A |

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## Electrical Characteristics:

| Characteristics | Symbol | Condition | Typ. | Max. | Units |
| :---: | :---: | :---: | :---: | :---: | :---: |
| Forward Voltage Drop* | $\mathrm{V}_{\mathrm{F} 1}$ | @ 30A, Pulse, $\mathrm{T}_{\mathrm{J}}=25^{\circ} \mathrm{C}$ <br> @ 60A, Pulse, $\mathrm{T}_{J}=25^{\circ} \mathrm{C}$ | $\begin{aligned} & 1.3 \\ & 1.6 \end{aligned}$ | $1.8$ | V |
| Reverse Current* | $\mathrm{I}_{\text {R1 }}$ | $\begin{aligned} & @ V_{R}=\text { rated } V_{R} \\ & T_{J}=25^{\circ} \mathrm{C} \end{aligned}$ | 0.13 | 50 | uA |
|  | $\mathrm{I}_{\mathrm{R} 2}$ | $\begin{aligned} & @ V_{R}=\text { rated } V_{R} \\ & T_{J}=125^{\circ} \mathrm{C} \end{aligned}$ | 0.12 | 1 | mA |
| Reverse Recovery Time | $\mathrm{tr}_{\text {r1 }}$ | $\mathrm{I}_{\mathrm{F}}=500 \mathrm{~mA}, \mathrm{I}_{\mathrm{R}}=1 \mathrm{~A}$, and $\mathrm{I}_{\mathrm{m}}=250 \mathrm{~mA}$ | 36 | 50 | ns |
| Reverse Recovery Time | $\mathrm{tr}_{\text {r2 }}$ | $\begin{aligned} & \mathrm{I}_{\mathrm{F}}=1 \mathrm{~A} ;-\mathrm{di} / \mathrm{dt}=200 \mathrm{~A} / \mathrm{\mu s} ; \\ & \mathrm{V}_{\mathrm{R}}=30 \mathrm{~V}, \mathrm{~T}_{\mathrm{C}}=25^{\circ} \mathrm{C} \end{aligned}$ | 40 | - | nS |
| Recovered Charge | $\mathrm{Q}_{\text {r }}$ | $\begin{aligned} & \mathrm{I}_{\mathrm{F}}=1 \mathrm{~A} ;-\mathrm{di} / \mathrm{dt}=200 \mathrm{~A} / \mathrm{\mu s} ; \\ & \mathrm{V}_{\mathrm{R}}=30 \mathrm{~V}, \mathrm{~T}_{\mathrm{C}}=25^{\circ} \mathrm{C} \end{aligned}$ | 58 | - | nC |

* Pulse width < $300 \mu \mathrm{~s}$, duty cycle $<2 \%$

Thermal-Mechanical Specifications:

| Characteristics |  | Symbol $^{2}$ | Condition | Specification |  | Units |
| :--- | :---: | :---: | :---: | :---: | :---: | :---: |
| Junction Temperature | $\mathrm{T}_{\jmath}$ | - | -55 to +175 | ${ }^{\circ} \mathrm{C}$ |  |  |
| Storage Temperature | $\mathrm{T}_{\text {stg }}$ | - | -55 to +175 | ${ }^{\circ} \mathrm{C}$ |  |  |
| Maximum Thermal <br> Resistance Junction to Case | $\mathrm{R}_{\text {өJc }}$ | DC operation | 0.34 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |  |  |
| Approximate Weight | wt | - | 6.7 | g |  |  |
| Case Style |  |  |  |  |  |  |

## SDUR60P60W

Figure 1


Figure 2
Typical Reverse Characteristics


Figure 3


SDUR60P60W

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Note: 1. $\mathrm{t}_{\mathrm{rr} 1}$ MIL-STD-750 Test Method 4031, condition "B".
2. $\mathrm{t}_{\mathrm{r} 2}$ MIL-STD-750 Test Method 4031, condition "D" .

Figure 4 - Reverse Recovery Waveform

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#### Abstract

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